



INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)

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Applicant(s)

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Filing Date

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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

"RF Memos Switches and Switch Circuits" Gabriel M. Rebeiz, Jeremy B. Muldavin, IEEE Microwave Magazine, December 2001 pages 59-71

"(Ba,Sr) TiO₃ dielectrics for future stacked-capacitor DRAM" by D.E. Kotecki, J.D. Banlecki, H. Shen, R.B. Lalbowitz, K.L. Saenger, J.J. Lian, T.M. Shaw, S.D. Athavale, C. Cabral, Jr., P.R. Duncombe, M. Gutsche, G. Kunkel, Y.-J. Park, Y.-Y. Wang, R. Wise, IBM J. Res. Develop. Vol 43 No. 3 May 1999

IBM Patent Application Number 60/339,089, filed 12/10/01, Christopher Jahnes, et al.

EXAMINER

Barclay Rojas

DATE CONSIDERED

02/10/04

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.